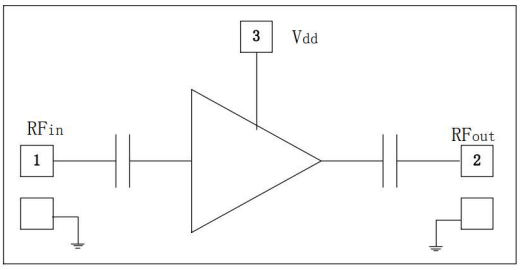
Performance

- Frequency: 0.8~18GHz
- Noise Figure: 3.0dB
- Typical Gain: 19dB
- Typical P-1: 14dBm
- $VSWR_{in/out}$: 1.5
- Voltage: V_d=+5V
- Technology: 0.15um Low Noise PHEMT
- Size: 3.3*1.8mm*0.1mm

Function Diagram

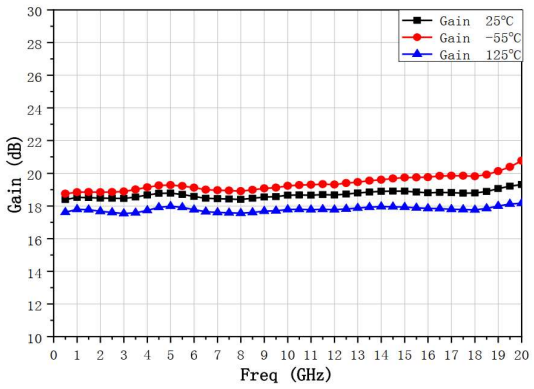


Electrical Specifications (V_d=5V, F: 0.8-18GHz)

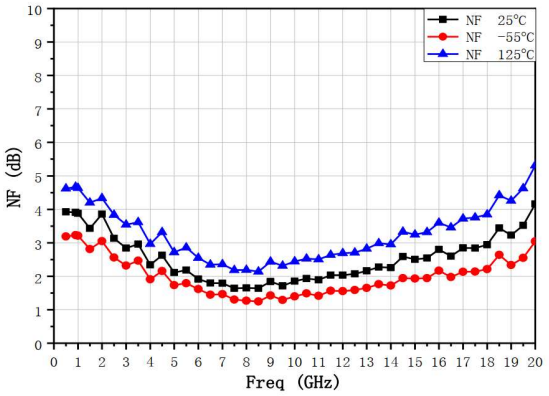
Symbol	Parameter	Min	Typical	Max	Unit
G	Small Signal Gain	16	19	23	dB
NF	Noise Figure	-	3.0	5.0	dB
$VSWR_{in}$	Input VSWR	-	1.7	2.2	-
$VSWR_{out}$	Output VSWR	-	1.5	2	-
P-1	P_{out} at 1dB compression	10	14	-	dBm
Id	Drain Current	-	85	100	mA

Test Curves

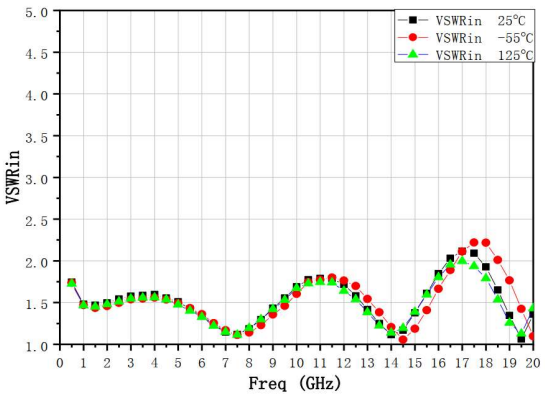
Small Signal Gain vs. Freq



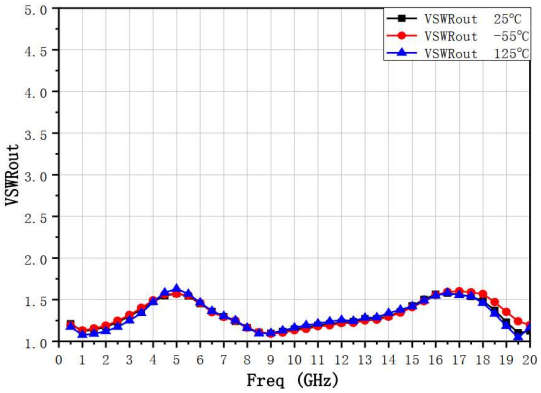
Noise Figure vs. Freq



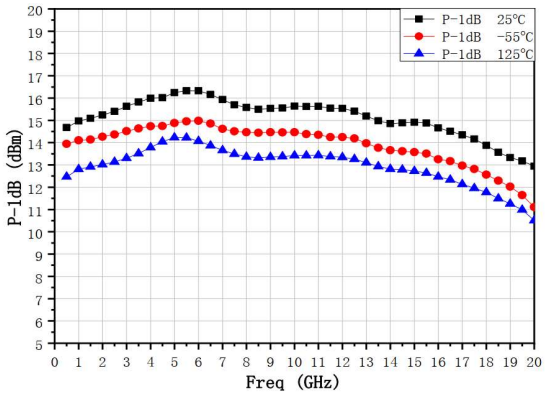
Input VSWR vs. Freq



Output VSWR vs. Freq



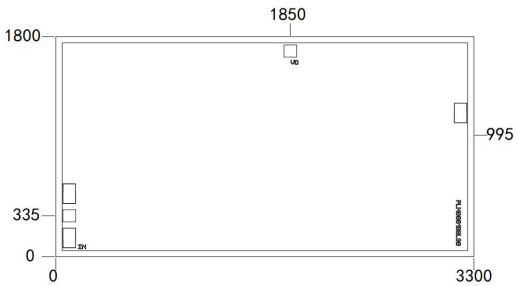
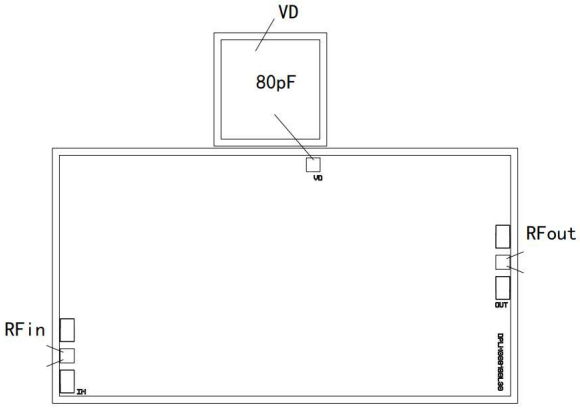
P-1dB vs. Freq



Absolute Max Ratings (T_A=25℃)

Symbol	Parameter	Value	Remark
Vd	Drain Voltage	7V	
Pin	Input Power	17dBm	
Tch	Channel Temperature	150℃	
Tm	Mounting Temperature	290℃	30sec, N_2 protection
Tstg	Storage Temperature	-55~150℃	

Exceeding any one or combination of these limits may cause permanent damage.

Outline Size (mm)	Assembly Diagram
	

Pin Definition

Number	Description
RFin	RF input port, connect to 50 ohm system, no block capacitor needed
RFout	RF output port, connect to 50 ohm system, no block capacitor needed
Vdd	Amplifier drain bias, connect to external 80pF capacitor
GND	Bottom must be well connected to RF and DC ground